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Picosecond pulsed laser for microscale sample preparation

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ABSTRACT

Ultra short pulsed laser ablation is applied for preparing samples suitable for micromechanical testing. Laue microdiffraction shows that the micromachining hardly damages the initial microstructure. The technique has the potential to be a promising alternative to focused ion beam preparation for micromechanical objects since it is relatively fast, efficient and implants no ions.

1. Introduction

Miniaturization of devices has made micromachining a necessity in materials science and engineering. Many small scale testing methods such as microcompression [1,2], uniaxial tensile testing [3], microcantilever testing [4] or microshear testing [5] use Focused Ion Beam milling (FIBing) as the main technique to prepare samples. It is reported that Ga⁺ ion implantation damages the material and can modify the microstructure (modification of dislocation structures, amorphization and/or formation of new intermetallic compounds) [2,6–9]. In order to get an adequate precision, low milling rate is needed. However for time constraints, it must be balanced with higher fluxes and energies, thus increasing the induced damage. Moreover, the milling rate depends strongly on the material and the crystallographic orientation [10,11]. Also, not all geometries are achievable by FIBing: for instance machining membranes (*i.e.* large, thin and deep areas

with high aspect ratio) with good reproducibility and low roughness is time consuming and simply inconceivable by FIBing.

Here, we apply Ultra Short Pulsed (USP) laser ablation for micromachining samples. Laser ablation consists in ejecting matter from the sample by irradiation with short, energetic bursts of light. Because only photons are used, less damage is expected in comparison with FIBing. The duration of the pulses has an important effect on the introduction of damage into the material: shorter pulse durations reduce the heat diffusion leading to low damage, better surface quality, improved resolution and higher precision [12]. Most of the pulse energy goes indeed into excitation of electrons which ablates the surrounding material with a very small Heat Affected Zone (HAZ) [12–16]. In the case of picosecond pulses, craters of ablation are clean and molecular dynamics simulations predict that the HAZ exhibits a negligible concentration of defects such as vacancies and dislocations [17]. More details on the mechanisms of laser ablation can be found in the supplementary data.

The objective of this work is to machine out of a bulk material 10 µm thin membranes with a diameter of a few hundreds of micrometers. Further imposed requirements are: (1) the roughness of the thinned area must be low, preferable a few hundreds of nanometers (2) a perfect control of the position of the membrane with high accuracy and reproducibility of the order of few micrometers; (3) the damage introduced during ablation must be minimized as much as possible. In this work the latter is verified by Laue x-ray microdiffraction.

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Table 1

Laser details and ablation parameters. (SHG: Second Harmonic Generation ; THG: Third Harmonic Generation).

Manufacturer	Lumera (now Coherent), Kaiserslautern, Germany
Model	Super rapid with SHG, THG and first pulse killer
Maximal power at 355 nm	~4 W
Maximum repetition rate	640 kHz
Material removal method	Layered ablation
Process gas	Ambient air
Wavelength	355 nm
Pulse duration	10 ps
Power	50 \pm 2 mW
Frequency	50 kHz
Focal spot size	~5 μm

2. Thinning down by picosecond pulsed laser ablation

Different materials purchased from Goodfellow were used: polycrystalline copper ("PolyCu") for optimizing the ablation parameters and monocrystalline copper ("MonoCu") for studying potential induced damage. In the case of MonoCu, ablation was made on several samples with the ablated surfaces parallel to $(\bar{1} \ 0 \ 0)$, $(0 \ 1 \ 4)$ and $(2 \ 2 \bar{1})$.

MonoCu samples were cut by electrical discharge machining to a thickness of 100 μm . All sample surfaces were then electro-polished to remove damage in the external layers. Finally, the samples were annealed at 1120 K, followed by slow cooling to room temperature in about 20 h.

For thinning down the sample laser pulses were directed by a galvano scanner in a cross hatch pattern towards the surface. To reduce the roughness, the distance between hatch lines was set exactly to 3 digitizing units ($\sim 4 \mu\text{m}$) of the Digital-to-Analog Converter (DAC) for the galvano scanner to reduce aliasing effects. Additionally the hatch direction was constantly rotated by 60°. $\sim 300 \text{ nm}$ per hatch is ablated with the parameters listed in Table 1. The first trials revealed that the perimeter of the membrane was more deeply thinned than the center, thus forming a trench. The depth of this trench increases with the amount of material ablated. Therefore to avoid trenching, the

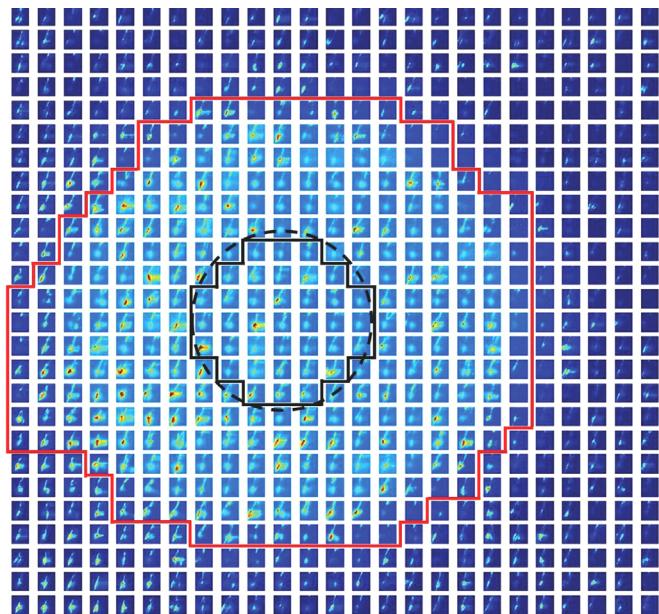
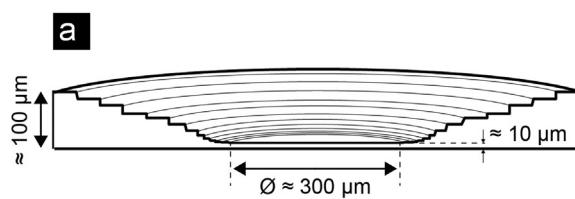


Fig. 2. 2D logarithmic scale diffraction map of the (131) reflection of the MonoCu $\sim (\bar{1} \ 0 \ 0)$ around the ablated zone. The pattern outside the red line are used to calculate the averaged values in the row "Out" of Table 2 and the ones inside the black line for the row "In" of Table 2. The area "In" corresponds to a circle with 120 μm diameter. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of this article.)

thinning process was done in a staircase concept as shown in Fig. 1a.

Fig. 1b shows a Scanning Electron Microscope (SEM) image of the membrane machined on PolyCu, and Fig. 1c provides the average membrane thicknesses measured by focal depth difference with an optical microscope (Olympus BX51). The root-mean-square (RMS) roughness of the thinned areas was determined with a white light interferometric microscope: an RMS roughness of about 500 nm was obtained for a length of $\sim 280 \mu\text{m}$ per sample. Moreover, membranes are flat as illustrated in Fig. 1d by the 3D topography view of the thinned PolyCu sample.



Cu		Average thickness (μm) $\pm 2 \mu\text{m}$
		$\pm 2 \mu\text{m}$
	Polycrystalline	12.0
	$\sim (\bar{1} \ 0 \ 0)$	10.9
	$\sim (0 \bar{1} \ 4)$	11.4
	$\sim (2 \ 2 \bar{1})$	10.9

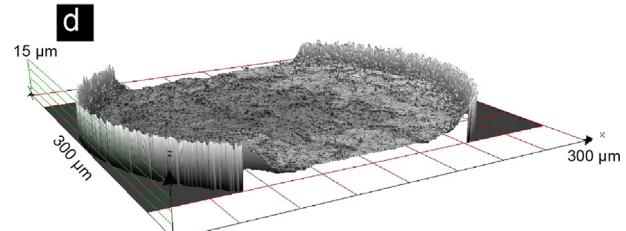
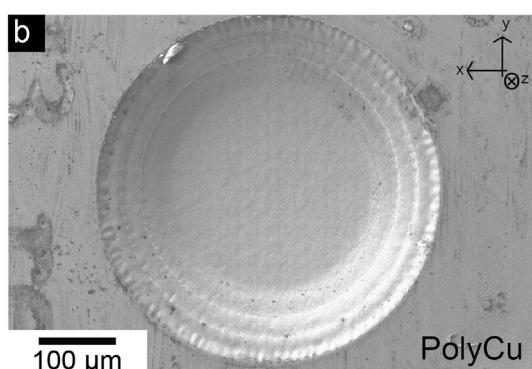


Fig. 1. (a) Sketch of the thinning procedure; (b) SEM image of the ablated area on polycrystalline copper; (c) membrane thickness; (d) 3D view of the topography of the ablated area in polycrystalline copper.

Table 2

Widths along 2θ and ψ directions for each observed spot. \bar{x} represents the mean value.

		Monocrystalline Cu $\sim(\bar{1}00)$					Monocrystalline Si								
		(1̄31)	(1̄3̄3)	(00̄2)	(13̄1)	\bar{x}	(3̄11)	(3̄1̄1)	(̄131)	(1̄3̄1)	(̄1̄31)	(311)	(̄311)	(̄3̄31)	\bar{x}
In	$\Delta 2\theta$ (°)	0.15	0.21	0.11	0.10	0.14	0.08	0.11	0.09	0.11	0.06	0.08	0.08	0.10	0.09
	$\Delta\psi$ (°)	0.19	0.15	0.14	0.11	0.15	0.06	0.07	0.07	0.07	0.11	0.06	0.05	0.07	0.07
Out	$\Delta 2\theta$ (°)	0.15	0.21	0.11	0.10	0.14									
	$\Delta\psi$ (°)	0.19	0.15	0.14	0.11	0.15									

3. Damage analysis by transmission x-ray Laue microdiffraction

Laue microdiffraction is a powerful technique for evaluating defect microstructures: the spot broadening is sensitive to crystal orientation gradients and deviatoric strains, generally resulting from the density of Geometrical Necessary Dislocations (GND) in the probed volume [8,18–20]. The experiments are performed at the MicroXAS beamline of the Swiss Light Source. 2D spatially resolved diffraction patterns over the membranes are recorded with a white micro-beam in transmission mode. More details of this beamline and the experiment can be found in [2,8] and in the supplementary data. In the following, diffraction results for MonoCu $\sim(\bar{1}00)$ are given.

An area of $500 \times 500 \mu\text{m}^2$ is scanned with a step size of $20 \mu\text{m}$ along x and y axis over the ablated membrane (Fig. 2). The Full-Widths at Half-Maximum (FWHM) along radial (2θ) and azimuthal (ψ) directions for each reflection in every patterns are calculated by fitting with a Pearson VII and their mean value can be found in Table 2. Comparison is made between patterns acquired inside and outside the ablated membrane. The averages $\overline{\Delta 2\theta}$ and $\overline{\Delta\psi}$ are respectively 0.14° and 0.15° inside the membrane, and 0.18° and 0.22° outside the membrane which are even slightly higher than the former. These results are analog to those obtained in a damage-free $10 \mu\text{m}$ thick monocrystalline Si (Table 2) acquired under the same diffraction conditions ($\overline{\Delta 2\theta}=0.09^\circ$ and $\overline{\Delta\psi}=0.07^\circ$). Similar results are obtained for other monocrystalline samples. Considering the challenging requirements, these results show that the preparation procedure based on picosecond pulsed laser ablation does not introduce important damage changing the shape of peak the profiles, as compared to samples prepared by FIBing [8,9,20].

4. Conclusions

In summary, a novel strategy based on USP laser ablation is developed to machine large thin flat areas. Only few tens of minutes are needed to machine membranes, which is an enormous advantage compared to FIB. Laue microdiffraction demonstrates that the induced damage is minimal. Consequently, USP laser ablation has a high potential to replace FIB in many applications related to small scale mechanical testing and opens new possibilities for machining new geometries.

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Appendix A. Supplementary information

Supplementary data associated with this article can be found in the online version at <http://dx.doi.org/10.1016/j.matlet.2015.06.119>.

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